NSN 5962-01-483-3306

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Maximum Power Dissipation Rating:
330.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Mams kit
Features Provided:
Monolithic and ultraviolet erasable
Inclosure Configuration:
Dual-in-line Dual-in-line
Product Name:
Eprom, programmed for navy micro panel
Voltage Rating And Type Per Characteristic:
-0.6 volts power source and 7.0 volts power source
Memory Device Type:
Eprom
Special Features:
This item is to be built in accordance with smd 5962-9175204mxa; next higher assembly ddg51; base part 031-01677-000
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
32 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A458a0